TOSHIBA

Optical Communication Devices 10 Gb/s Optical Receiver

TOPD371-RXSW Series



APPLICATIONS

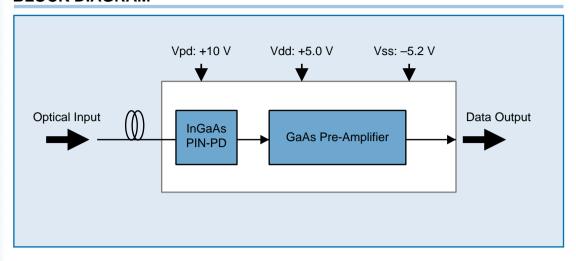
- SONET / SDH (OC-192 / STM-64) applications
- WDM system applications

FEATURES

- PIN-PD and Pre-amplifier
- K-connector output
- Sensitivity: -19 dBm (typ. @ BER = 1 x 10^{-12} , 10.6642 Gb/s, RZ, PRBS 2^{31} –1)
- Overload: + 1 dBm (min @ BER = 1 x 10⁻¹², 10.6642Gb/s, RZ, PRBS 2³¹–1)
- Transimpedance: 700 Ω (typ.)
- Groupe Delay (GD) deviation –10 to + 30 ps
- Output electrical return loss: 15dB (typ.)

TOPD371-RXSW Series

BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Ratings	Unit
Storage temperature	Tstg	- 40, + 85	°C
Operating case temperature	Tc	0, + 70	°C
PD forward current	If	3	mA
PD reverse current	Ir	2	mA
PD reverse voltage	Vpd	0 to +20	V
Positive supply voltage	Vdd	- 0.5 to +6.5	V
Negative supply voltage	Vss	- 7 to +0.5	V
Positive supply current	ldd	100	mA
Soldering temperature	Tsol	260 / 5	°C/s

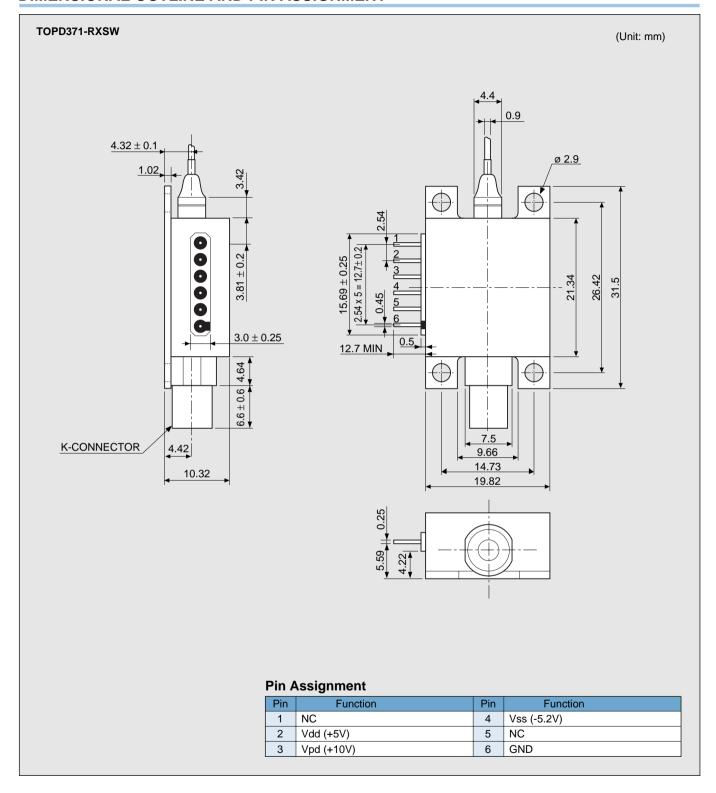
ELECTRICAL AND OPTICAL CHARACTERISTICS (Tc = 0 to 70 $^{\circ}$ C , λ = 1.55 μ m, Vdd = + 5 V, Vpd = + 10 V, Vss = -5.2 V)

Item	Symbol	Conditions	Min	Тур.	Max	Unit
Total power consumption	_	_	-	300	_	mW
Positive supply current	ldd	_	-	50	_	mA
Responsivity	R _{1.55}	Pin = −14 dBm	0.68	0.75	_	A/W
Dark current	ld	_	_	_	10	nA
Cutoff frequency	fc	3dB down from 10MHz	7	-	12	GHz
Cutoff frequency (Low)	fc@	3dB down from 10MHz	-	-	100	kHz
Group delay (GD) deviation, Note 1	GD	-18dBm < Pin < +1dBm 300 kHz < f < fc	-10	_	+30	ps
Output signal level	_	−17dBm	_	30	_	mVpp
Output electrical return loss	S22	300 kHz < f < 8 GHz	12	15	_	dB
Sensitivity	Ps	Note 2	-	-19	_	dBm
Overload	Po	Note 2	+1	_	_	dBm
Optical return loss	ORL	_	27	_	_	dB
Logic sense	_	Light "ON" = Output Logic "HIGH" (Logic "HIGH" is defined to be more positive than Logic "Low")	-	_	_	_
Transimpedance	Zt	Pin = -10dBm	500	700	_	Ω

Note 1: O/E Transfer function group delay (GD) deviation from GD at low frequency

Note 2: 10.6642Gb/s, RZ, PRBS2³¹-1, BER = 10^{-12}

DIMENSIONAL OUTLINE AND PIN ASSIGNMENT



PRECAUTIONS

- (a) Power supply: Transient electric spike may cause a damage to the photodiode or IC chips.
 A surge-free power supply and a slow starter circuit should be used.
 To avoid causing an electrical surge, pins should not be connected or disconnected on the test fixture before turning power off.
- (b) The product should be grounded for obtaining the performance.

Toshiba America Electronic Components, Inc.

Headquarters-Irvine, CA

9775 Toledo Way, Irvine, CA 92618, U.S.A. Tel: (949)455-2000 Fax: (949)859-3963

Deerfield, IL(Chicago)

One Pkwy., North, Suite 500, Deerfield, IL 60015, U.S.A.

Tel: (847)945-1500 Fax: (847)945-1044

Edison, NJ

2035 Lincoln Hwy. #3000, Edison. NJ 08817, U.S.A. Tel: (732)248-8070 Fax: (732)248-8030

Raleigh, NC

5511 Capitol Center Dr., #114. Raleigh, NC 27606, U.S.A. Tel: (919)859-2800 Fax: (919)859-2898

Richardson, TX(Dallas)

777 East Campbell Rd., #650, Richardson, TX 75081, U.S.A.

Tel: (972)480-0470 Fax: (972)235-4114

Wakefield, MA(Boston)

401 Edgewater Place, #360, Wakefield, MA 01880 U.S.A Tel: (781)224-0074 Fax: (781)224-1095

Toshiba Electronics Europe GmbH

Düsseldorf Head Office

Hansaallee 181, D-40549 Düsseldorf, Germany

Tel: (0211)5296-0 Fax: (0211)5296-400

Toshiba Electronics Italiana S.R.L.

Centro Direzionale Colleoni, 1-20041 Agrate Brianza, (Milan), Italy Tel: (039)68701 Fax:(039)6870205

Toshiba Electronics(UK) Ltd.

Riverside Way, Camberley Surrey, GU15 3YA, U.K.

Tel: (01276)69-4600 Fax: (01276)69-4800

Toshiba Electronics Scandinavia A.B.

Gustavslundsvägen 12, 2nd Floor, S-161 15 Bromma, Sweden Tel: (08)704-0900 Fax: (08)80-8459

Toshiba Electronics Asia (Singapore) Pte. Ltd.

Singapore Head Office

438B Alexandra Road, #06-08/12 Alexandra Technopark, Singapore 119968 Tel: (278)5252 Fax: (271)5155

Toshiba Electronics Asia, Ltd.

Hong Kong Head Office

Level 11, Tower 2, Grand Century Place No 193 Prince Edward Road West Mong Kok, Kowloon, Hong Kong Tel: 2375-6111 Fax: 2375-0969

Beijing Office

Rm 714, Beijing Fortune Building, No.5 Dong San Huan Bei-Lu, Chao Yang District, Beijing, 100004, China Tel: (010)6590-8796 Fax: (010)6590-8791

Toshiba Electronics Korea Corporation

Seoul Head Office

14/F KEC B/D 275-7 Yangiae-dong Seocho-ku, Seoul, Korea Tel: (02)589-4300 Fax: (02)589-4302

Toshiba Technology Development (Shanghai) Co., Ltd.

23F, HSBC Tower, 101 Yin Cheng East Road, Pudong New Area, Shanghai, 200120. China Tel: (021)6841-0666 Fax: (021)6841-5002

Toshiba Electronics Taiwan Corporation

Taipei Head Office

17F, Union Enterprise Plaza Bldg. 109 Min Sheng East Rd., Section 3, 10446 Taipei, Taiwan Tel: (02)2514-9988 Fax: (02)2514-7892

(As of August, 2001)

The information contained herein is subject to change without notice

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.

TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

The Toshiba products listed in this document are intended for usage in general electronics applications (computer, personal equipment,

office equipment, measuring equipment, industrial robotics, domestic appliances, etc.).

These Toshiba products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of Toshiba products listed in this document shall be made at the customeris own risk.



TOSHIBA CORPORATION

Electronic Devices Sales & Marketing Division 1-1, Shibaura 1-chome, Minato-ku, Tokyo, 105-8001, Japan Tel: +81-3-3457-3405 Fax: +81-3-5444-9431

The products described in this document are subject to the foreign exchange and foreign trade laws.

Gallium arsenide (GaAs) is a substance used in some of the products described in this documents. GaAs dust and fumes are toxic. Do not break, cut or pulverize the products, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage

Website: http://www.semicon.toshiba.co.jp/eng/index.html